

Isc N-Channel MOSFET Transistor

IPA65R1K5CE

FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- Reduced switching and conduction losses
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



Switching applications

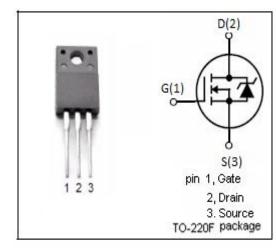


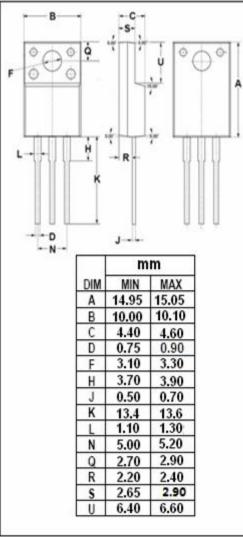
 ABSOLUTE 	MAXIMUM	RATINGS(T	a=25°C
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/ LDC 2012 III DAING III TO TITUCO (Ta 20 C)				
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	650	V	
V _{GSS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-Continuous @Tc=25°C (V _{GS} at 10V) Tc=100°C	5.2 3.3	А	
I _{DM}	Drain Current-Single Pulsed	8.3	А	
P_D	Total Dissipation @T _C =25℃	30	W	
Tj	Max. Operating Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	4.2	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =1mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =0.1mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =1A		1260	1500	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V;Tj=25°C V _{DS} = 650V; V _{GS} = 0V; Tj=150°C			1 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =1.5A, V _{GS} = 0V		0.9		V

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